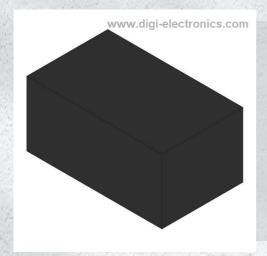


# PDTC144TM,315 Datasheet



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DiGi Electronics Part Number PDTC144TM,315-DG

Manufacturer NXP Semiconductors

Manufacturer Product Number PDTC144TM,315

Description TRANS PREBIAS

Detailed Description Pre-Biased Bipolar Transistor (BJT)



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# **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
PDTC144TM,315	NXP Semiconductors
Series:	Product Status:
*	Active
Base Product Number:	
PDTC144	

# **Environmental & Export classification**

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected

## **DISCRETE SEMICONDUCTORS**

# DATA SHEET

# **PDTC144T series** NPN resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = open

Product data sheet Supersedes data of 2004 Apr 06 2004 Aug 17



## NPN resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = open

## PDTC144T series

#### **FEATURES**

- Built-in bias resistors
- · Simplified circuit design
- Reduction of component count
- · Reduced pick and place costs.

#### **APPLICATIONS**

- General purpose switching and amplification
- · Inverter and interface circuits
- · Circuit driver.

#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V <sub>CEO</sub>	collector-emitter voltage	_	50	V
Io	output current (DC)	_	100	mA
R1	bias resistor	47	_	kΩ
R2	open	_	_	_

### **DESCRIPTION**

NPN resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

#### PRODUCT OVERVIEW

TYPE NUMBER	PACK	AGE	MARKING CODE	PNP COMPLEMENT
ITPE NUMBER	PHILIPS	EIAJ	MARKING CODE	PNP COMPLEMENT
PDTC144TE	SOT416	SC-75	43	PDTA144TE
PDTC144TEF	SOT490	SC-89	33	PDTA144TEF
PDTC144TK	SOT346	SC-59	53	PDTA144TK
PDTC144TM	SOT883	SC-101	E4	PDTA144TM
PDTC144TS	SOT54 (TO-92)	SC-43	TC144T	PDTA144TS
PDTC144TT	SOT23	_	*41 <sup>(1)</sup>	PDTA144TT
PDTC144TU	SOT323	SC-70	*41 <sup>(1)</sup>	PDTA144TU

### Note

<sup>1. \* =</sup> p: Made in Hong Kong.

<sup>\* =</sup> t: Made in Malaysia.

<sup>\* =</sup> W: Made in China.

# NPN resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = open

## PDTC144T series

## SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL		PINNING
ITPE NUMBER	SIMPLIFIED OUTLINE AND STMBOL	PIN	DESCRIPTION
PDTC144TS		1	base
		2	collector
	1 R1 R1 3 MAM361	3	emitter
PDTC144TE PDTC144TEF PDTC144TK PDTC144TT PDTC144TU	3 1 R1 2 Top view  MDB270	1 2 3	base emitter collector
PDTC144TM		1	base
		2	emitter
	2 R1 3 Bottom view MHC507	3	collector

## NPN resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = open

## PDTC144T series

#### **ORDERING INFORMATION**

TYPE NUMBER	PACKAGE							
ITPE NUMBER	NAME	DESCRIPTION	VERSION					
PDTC144TE	-	plastic surface mounted package; 3 leads	SOT416					
PDTC144TEF	_	plastic surface mounted package; 3 leads	SOT490					
PDTC144TK	_	plastic surface mounted package; 3 leads	SOT346					
PDTC144TM	_	leadless ultra small plastic package; 3 solder lands; body $1.0 \times 0.6 \times 0.5 \text{ mm}$	SOT883					
PDTC144TS	_	plastic single-ended leaded (through hole) package; 3 leads	SOT54					
PDTC144TT	_	plastic surface mounted package; 3 leads	SOT23					
PDTC144TU	_	plastic surface mounted package; 3 leads	SOT323					

### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	5	V
Io	output current (DC)		_	100	mA
I <sub>CM</sub>	peak collector current		-	100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$			
	SOT54	note 1	_	500	mW
	SOT23	note 1	_	250	mW
	SOT346	note 1	_	250	mW
	SOT323	note 1	_	200	mW
	SOT490	notes 1 and 2	_	250	mW
	SOT883	notes 2 and 3	_	250	mW
	SOT416	note 1	_	150	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>j</sub>	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature	_	-65	+150	°C

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#### **Notes**

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60  $\mu m$  copper strip line.

## NPN resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = open

## PDTC144T series

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air		
	SOT54	note 1	250	K/W
	SOT23	note 1	500	K/W
	SOT346	note 1	500	K/W
	SOT323	note 1	625	K/W
	SOT490	notes 1 and 2	500	K/W
	SOT883	notes 2 and 3	500	K/W
	SOT416	note 1	833	K/W

#### **Notes**

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60  $\mu m$  copper strip line.

### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0 A	_	_	100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$	_	_	1	μΑ
		$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}; T_{j} = 150 ^{\circ}\text{C}$	_	_	50	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A	_	_	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 1 mA	100	_	_	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	_	-	150	mV
R1	input resistor		33	47	61	kΩ
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0 \text{ A}; V_{CB} = 10 \text{ V};$ f = 1 MHz	_	_	2.5	pF

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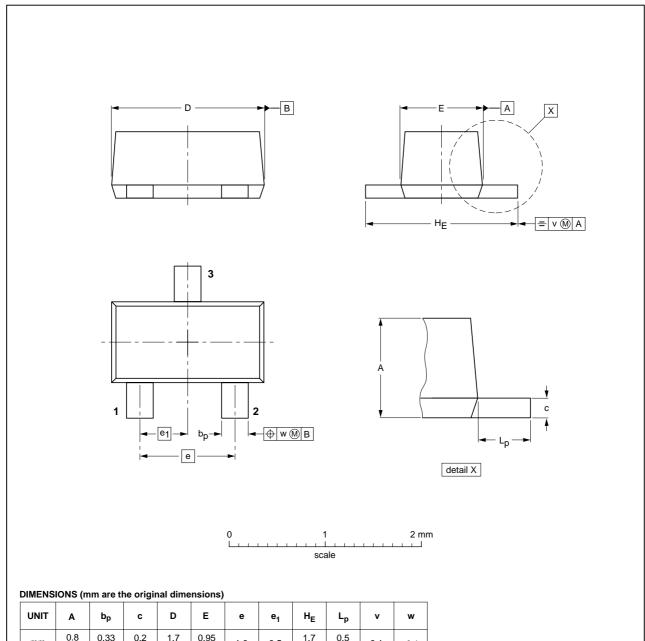
# NPN resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = open

## PDTC144T series

#### **PACKAGE OUTLINES**

## Plastic surface-mounted package; 3 leads

**SOT490** 



UNIT	Α	bp	С	D	E	е	e <sub>1</sub>	HE	L <sub>p</sub>	v	w
mm	0.8 0.6	0.33 0.23	0.2 0.1	1.7 1.5	0.95 0.75	1.0	0.5	1.7 1.5	0.5 0.3	0.1	0.1

OUTLINE		REFER				
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT490			SC-89			<del>05-07-28</del> 06-03-16

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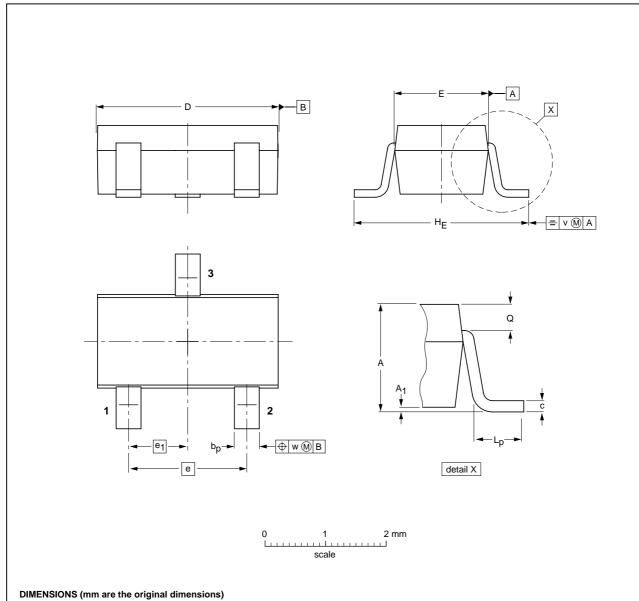
2004 Aug 17

# NPN resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = open

## PDTC144T series

## Plastic surface-mounted package; 3 leads

**SOT346** 



UNIT	Α	A <sub>1</sub>	bp	С	D	E	е	e <sub>1</sub>	HE	Lp	Q	v	w
mm	1.3 1.0	0.1 0.013	0.50 0.35	0.26 0.10	3.1 2.7	1.7 1.3	1.9	0.95	3.0 2.5	0.6 0.2	0.33 0.23	0.2	0.2

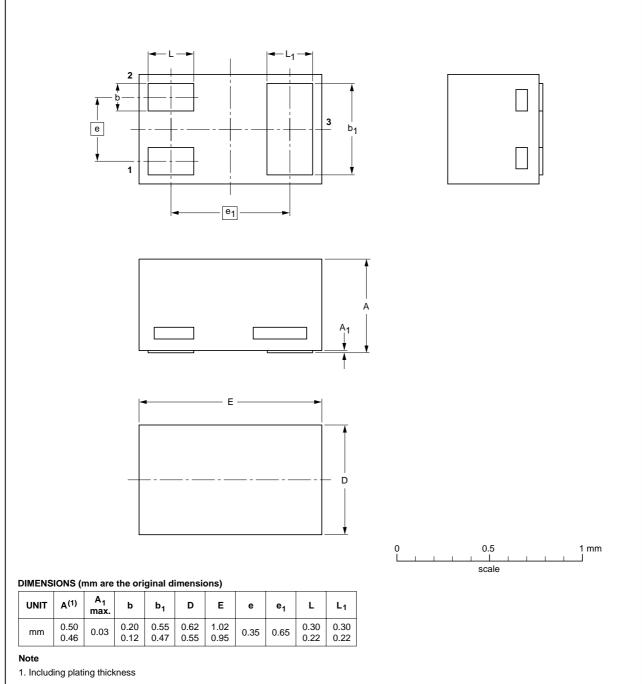
OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT346		TO-236	SC-59A		<del>04-11-11</del> 06-03-16

## NPN resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = open

## PDTC144T series

## Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

**SOT883** 



OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT883			SC-101		<del>03-02-05</del> 03-04-03

8

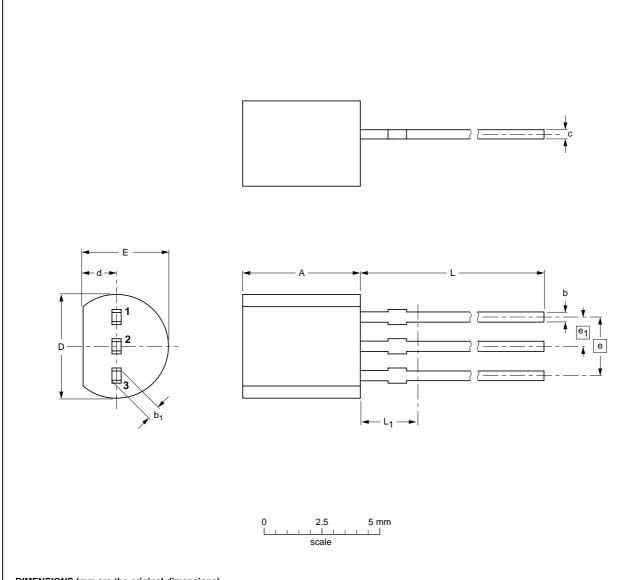
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# NPN resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = open

## PDTC144T series

## Plastic single-ended leaded (through hole) package; 3 leads

SOT54



### **DIMENSIONS (mm are the original dimensions)**

UNIT	Α	b	b <sub>1</sub>	С	D	d	E	е	e <sub>1</sub>	L	L <sub>1</sub> <sup>(1)</sup> max.	
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5	

#### Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT54		TO-92	SC-43A		<del>-04-06-28-</del> 04-11-16

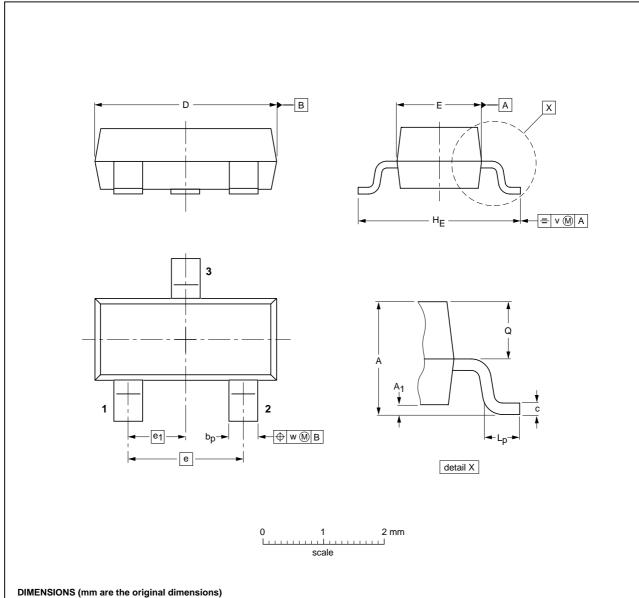
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# NPN resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = open

## PDTC144T series

## Plastic surface-mounted package; 3 leads

SOT23



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U	NIT	Α	A <sub>1</sub> max.	bp	С	D	E	е	e <sub>1</sub>	HE	Lp	Q	v	w
n	nm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

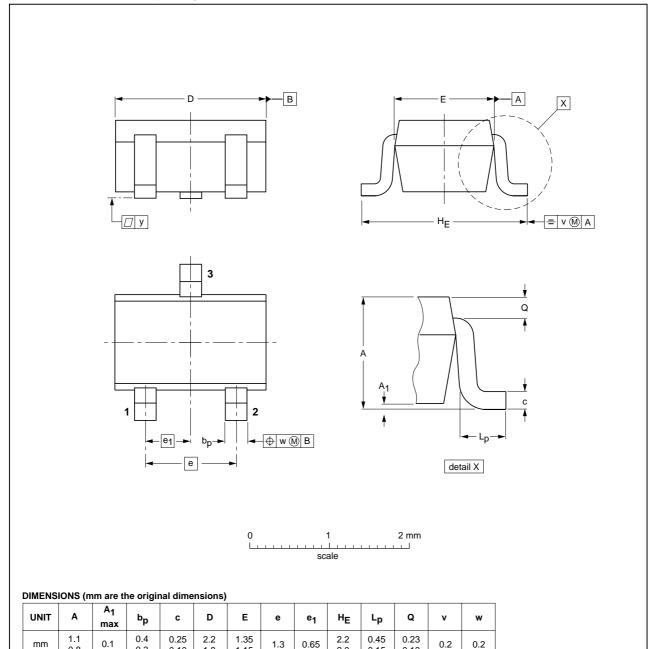
OUTLINE		REFER	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT23		TO-236AB			<del>-04-11-04</del> 06-03-16

## NPN resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = open

## PDTC144T series

## Plastic surface-mounted package; 3 leads

SOT323



OUTLINE		REFER	ENCES	REFERENCES					
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE			
SOT323			SC-70			<del>04-11-04</del> 06-03-16			

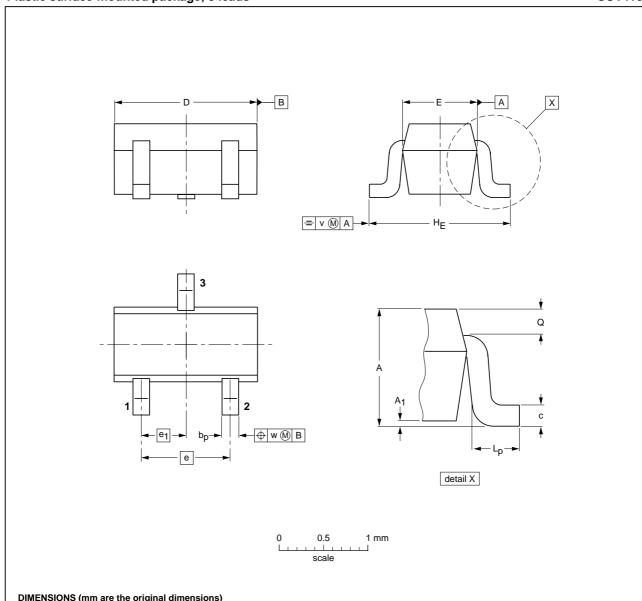
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# NPN resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = open

## PDTC144T series

## Plastic surface-mounted package; 3 leads

**SOT416** 



DIMENSIONS	(mm	are	the	original	dimensions	)
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UNIT	Α	A <sub>1</sub> max	bp	С	D	E	е	e <sub>1</sub>	HE	Lp	ø	v	w
mm	0.95 0.60	0.1	0.30 0.15	0.25 0.10	1.8 1.4	0.9 0.7	1	0.5	1.75 1.45	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT416			SC-75		<del>04-11-04</del> 06-03-16

## NPN resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = open

## PDTC144T series

#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

#### **Notes**

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#### **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

#### **Contact information**

For additional information please visit: http://www.nxp.com
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